

L Number	Hits	Search Text	DB	Time stamp
1	371054	semiconductor and ((thin adj film dj transistor) or tft)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 16:35
2	78826	(semiconductor and ((thin adj film dj transistor) or tft)) and (gate adj electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 16:36
3	60170	((semiconductor and ((thin adj film dj transistor) or tft)) and (gate adj electrode)) and source and drain and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 16:36
4	16618	((semiconductor and ((thin adj film dj transistor) or tft)) and (gate adj electrode)) and source and drain and electrode) and (contact adj hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 16:37
5	4505	((semiconductor and ((thin adj film dj transistor) or tft)) and (gate adj electrode)) and source and drain and electrode) and (contact adj hole)) and transparent and conduct\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 16:38
6	1372	((semiconductor and ((thin adj film dj transistor) or tft)) and (gate adj electrode)) and source and drain and electrode) and (contact adj hole)) and transparent and conduct\$3) and (light adj shield\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 16:38